

NP100P04PDG

-40V – -100A – P-channel Power MOS FET

R07DS1512EJ0101

Rev.1.01

Application : Automotive

Jul. 14, 2022

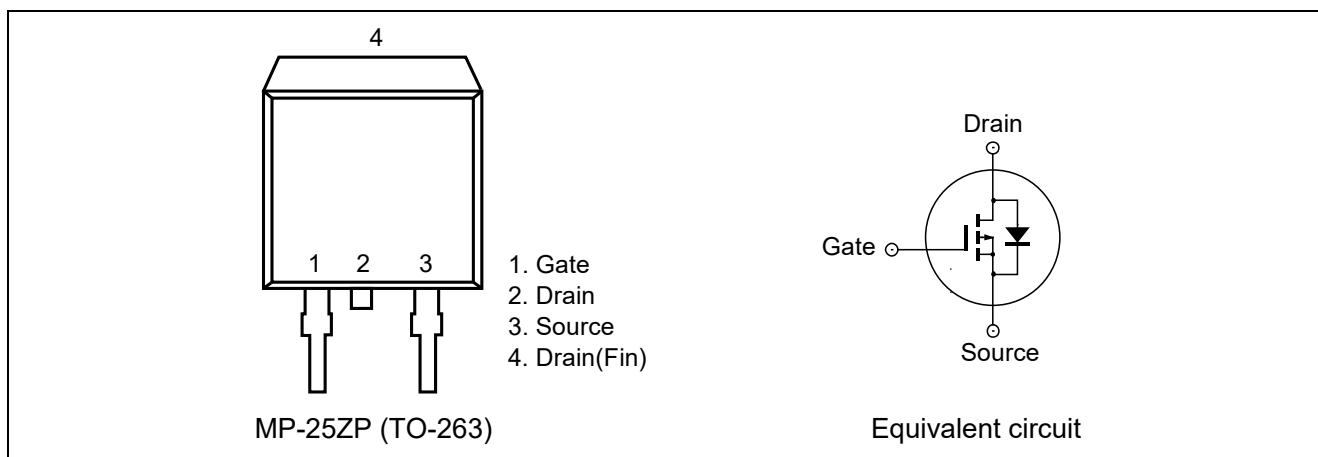
Description

This product is P-channel MOS Field Effect Transistor designed for high current switching applications.

Features

- Super low on-state resistance : $R_{DS(on)} = 3.5 \text{ m}\Omega \text{ Max. (} V_{GS} = -10 \text{ V, } I_D = -50 \text{ A)}$
 $R_{DS(on)} = 5.1 \text{ m}\Omega \text{ Max. (} V_{GS} = -4.5 \text{ V, } I_D = -50 \text{ A)}$
- Low input capacitance : $C_{iss} = 15100 \text{ pF Typ.}$
- Designed for automotive application and AEC-Q101 qualified.
- Pb-free (This product does not contain Pb in the external electrode)

Outline



Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to Source Voltage ($V_{GS} = 0 \text{ V}$)	V_{DSS}	-40	V
Gate to Source Voltage ($V_{DS} = 0 \text{ V}$)	V_{GSS}	± 20	V
Drain Current (DC) ($T_c = 25^\circ\text{C}$)	$I_{D(DC)}$	± 100	A
Drain Current (pulse)	$I_{D(pulse)}$ ^{Notes1}	± 300	A
Total Power Dissipation ($T_c = 25^\circ\text{C}$)	P_{T1}	200	W
Total Power Dissipation ($T_a = 25^\circ\text{C}$)	P_{T2}	1.8	W
Channel Temperature	T_{ch}	175	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to 175	$^\circ\text{C}$
Single Avalanche Current	I_{AS} ^{Notes2}	74	A
Single Avalanche Energy	E_{AS} ^{Notes2}	550	mJ

Notes 1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

2. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = -20\text{V}$, $R_G = 25 \Omega$, $V_{GS} = -20 \rightarrow 0\text{V}$, $L = 100\mu\text{H}$

Thermal Resistance

Channel to Case Thermal Resistance	$R_{th(ch-c)}$ ^{Notes3}	0.75	°C/W
Channel to Ambient Thermal Resistance	$R_{th(ch-a)}$ ^{Notes3}	83.3	°C/W

Electrical Characteristics

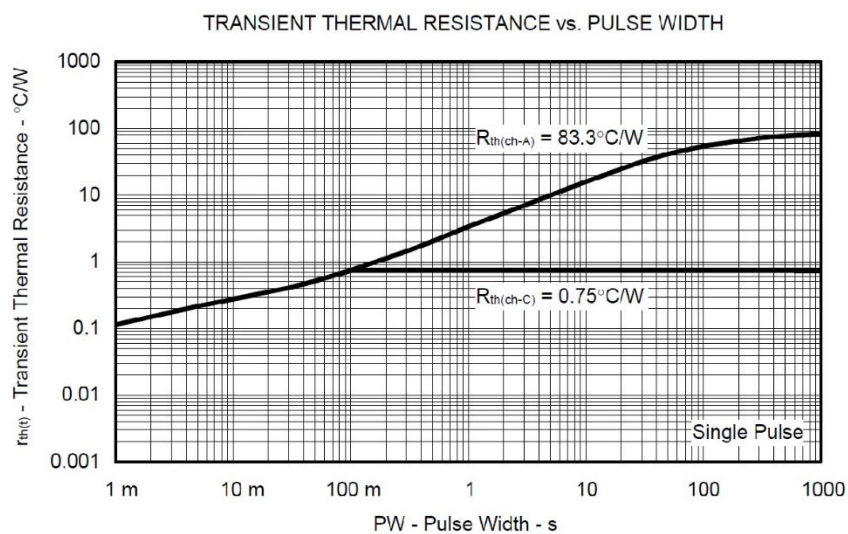
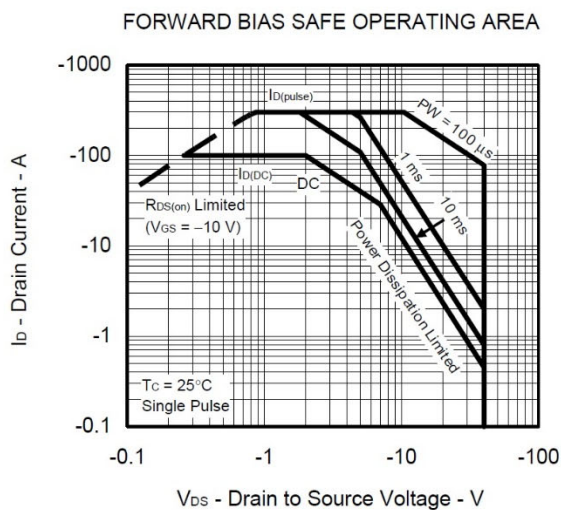
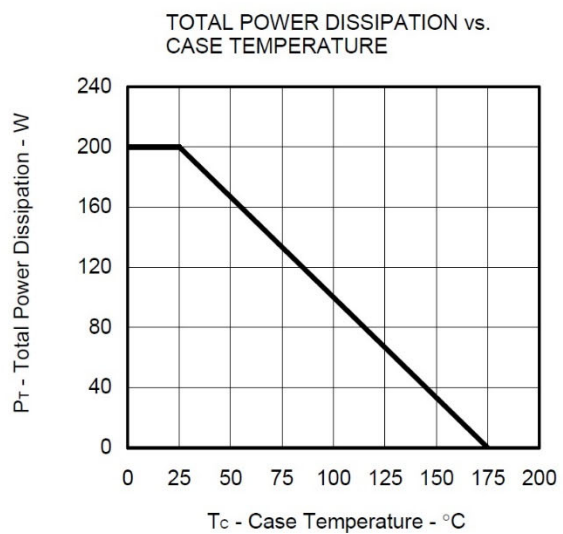
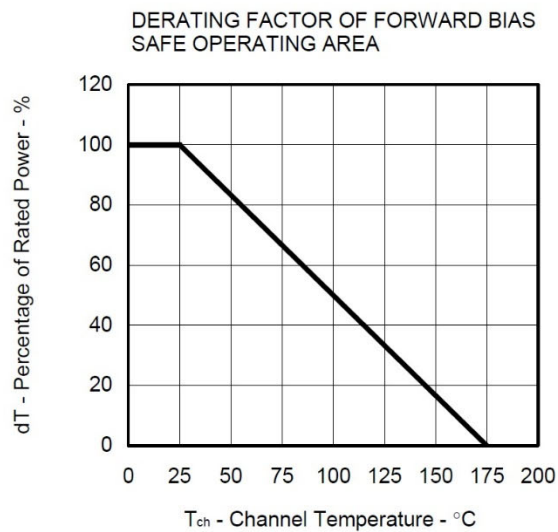
(T_a=25°C)

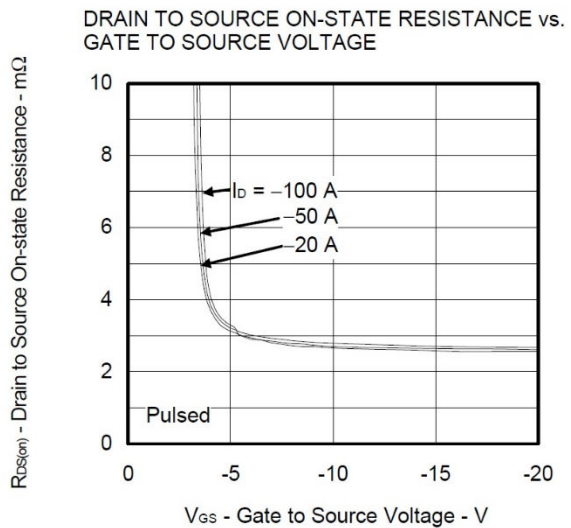
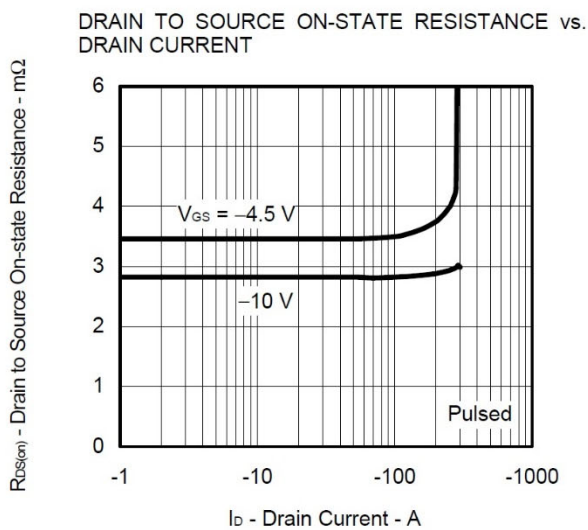
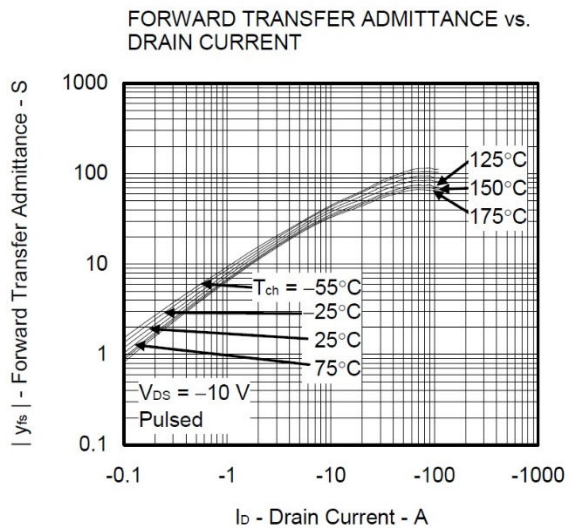
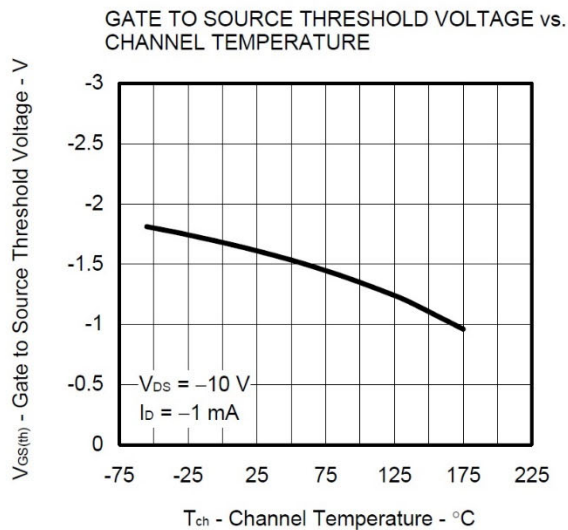
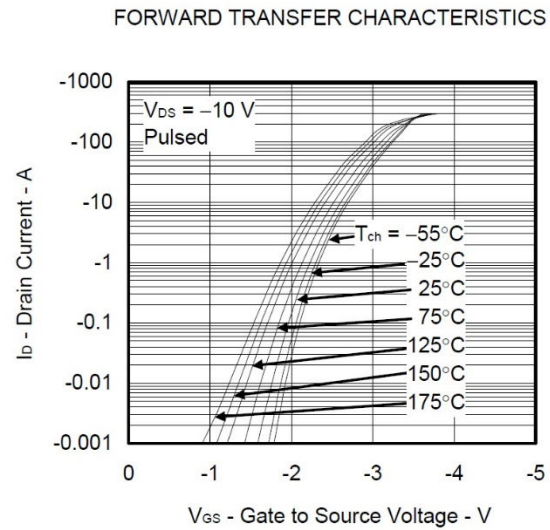
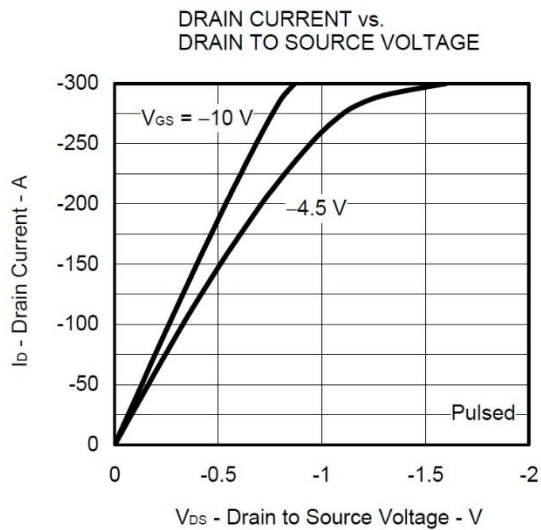
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero Gate Voltage Drain Current	I_{DSS}	—	—	-10	μA	$V_{DS} = -40\text{ V}$, $V_{GS} = 0\text{ V}$
Gate Leakage Current	I_{GSS}	—	—	±100	nA	$V_{GS} = \pm 20\text{ V}$, $V_{DS} = 0\text{ V}$
Gate to Source Threshold Voltage	$V_{GS(th)}$	-1.0	-1.6	-2.5	V	$V_{DS} = -10\text{ V}$, $I_D = -1\text{ mA}$
Forward Transfer Admittance	$ y_{fs} $ ^{Notes4}	43	88	—	S	$V_{DS} = -10\text{ V}$, $I_D = -50\text{ A}$
Drain to Source On-state Resistance	$R_{DS(on)1}$ ^{Notes4}	—	2.8	3.5	mΩ	$V_{GS} = -10\text{ V}$, $I_D = -50\text{ A}$
	$R_{DS(on)2}$ ^{Notes4}	—	3.4	5.1	mΩ	$V_{GS} = -4.5\text{ V}$, $I_D = -50\text{ A}$
Input Capacitance	C_{iss}	—	15100	—	pF	$V_{DS} = -10\text{ V}$
Output Capacitance	C_{oss}	—	2400	—	pF	$V_{GS} = 0\text{ V}$
Reverse Transfer Capacitance	C_{rss}	—	1130	—	pF	$f = 1\text{ MHz}$
Turn-on Delay Time	$t_{d(on)}$	—	38	—	ns	$V_{DD} = -20\text{ V}$
Rise Time	t_r	—	30	—	ns	$I_D = -45\text{ A}$
Turn-off Delay Time	$t_{d(off)}$	—	300	—	ns	$V_{GS} = -10\text{ V}$
Fall Time	t_f	—	100	—	ns	$R_G = 0\text{ }\Omega$
Total Gate Charge	Q_g	—	320	—	nC	$V_{DD} = -32\text{ V}$
Gate to Source Charge	Q_{gs}	—	37	—	nC	$V_{GS} = -10\text{ V}$
Gate to Drain Charge	Q_{gd}	—	85	—	nC	$I_D = -100\text{ A}$
Body Diode Forward Voltage	$V_{F(S-D)}$ ^{Notes4}	—	0.91	1.5	V	$I_F = -100\text{ A}$, $V_{GS} = 0\text{ V}$
Reverse Recovery Time	t_{rr}	—	70	—	ns	$I_F = -100\text{ A}$, $V_{GS} = 0\text{ V}$
Reverse Recovery Charge	Q_{rr}	—	123	—	nC	$di/dt = -100\text{ A}/\mu\text{s}$

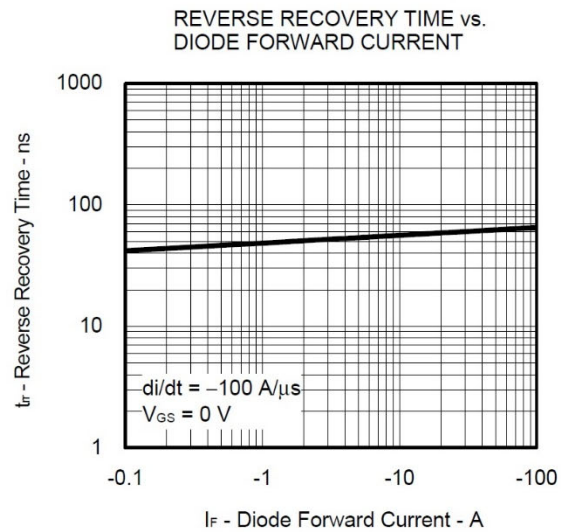
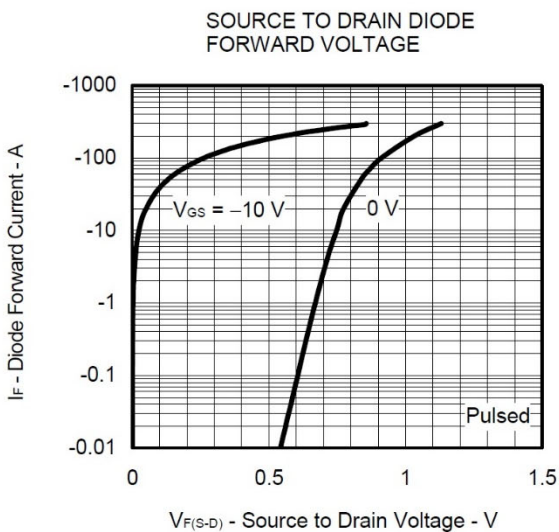
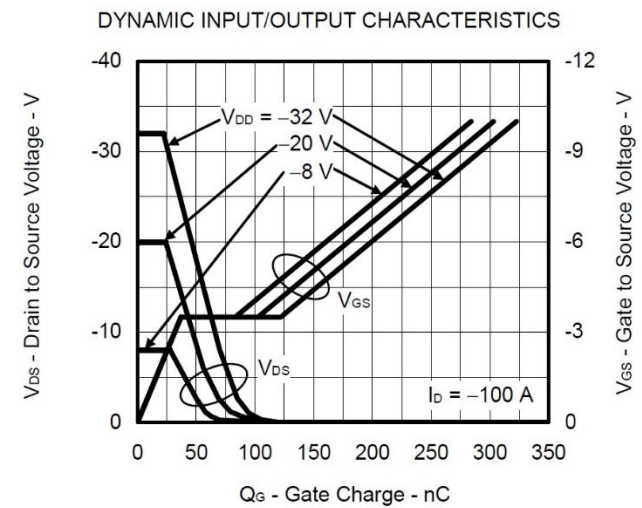
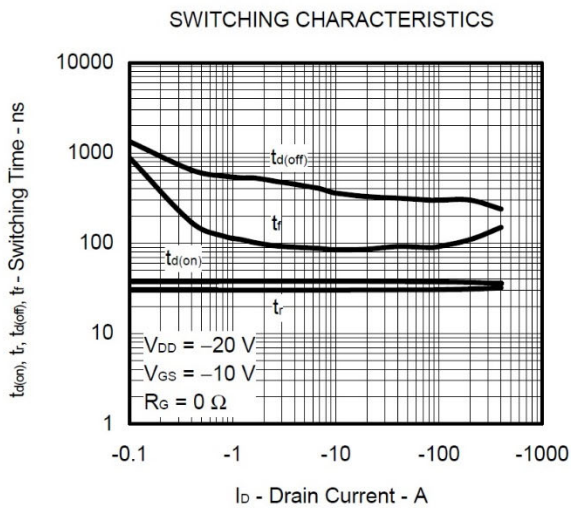
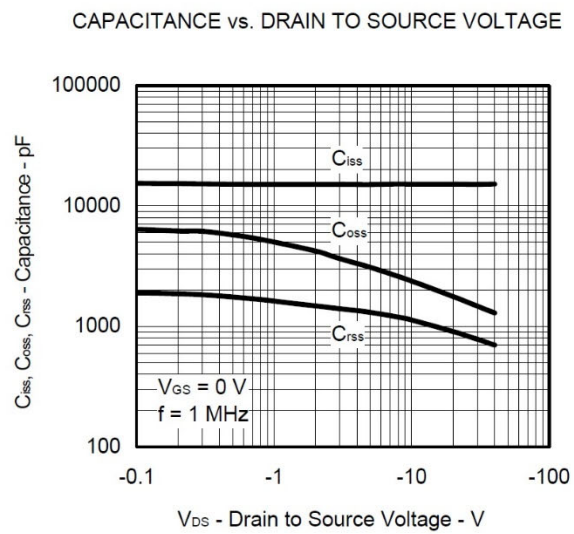
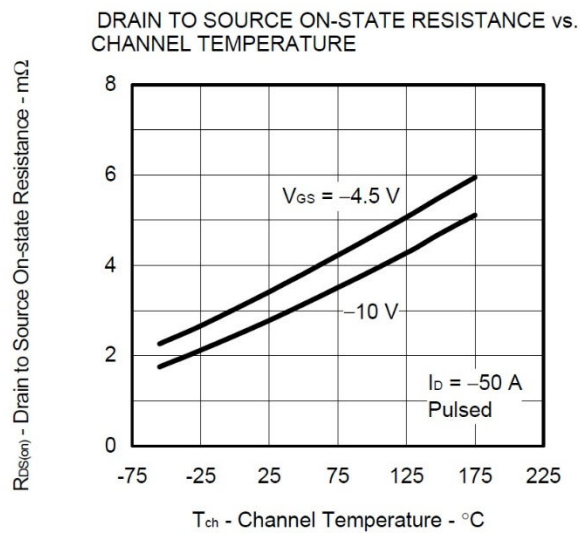
Notes 3. Designed target value on Renesas measurement condition. Not subject to production test.

4. Pulse test.

Typical Characteristics



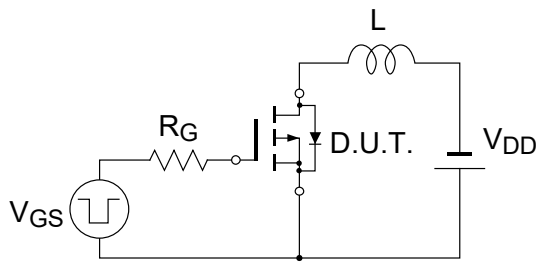




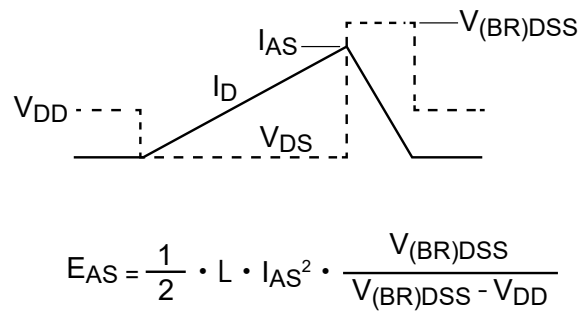
Test Circuit

Avalanche

Test Circuit

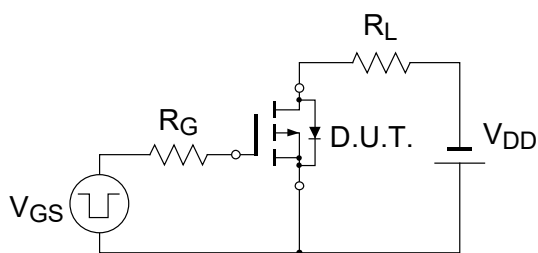


Waveform

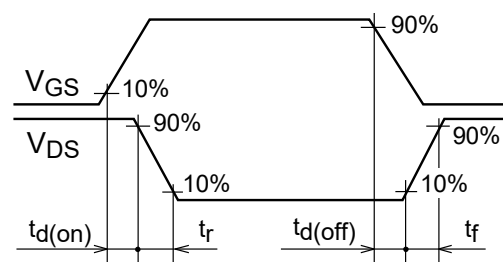


Switching Time

Test Circuit

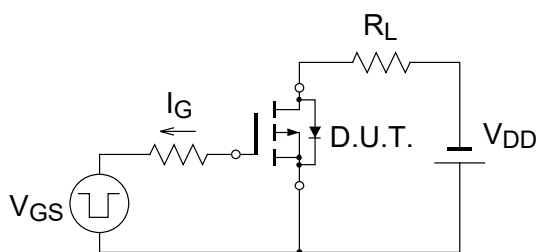


Waveform

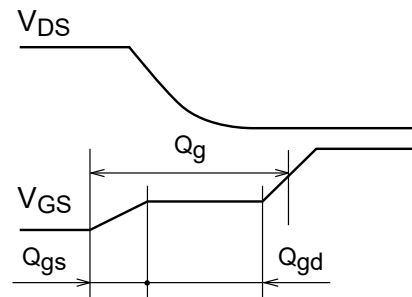


Gate Charge

Test Circuit

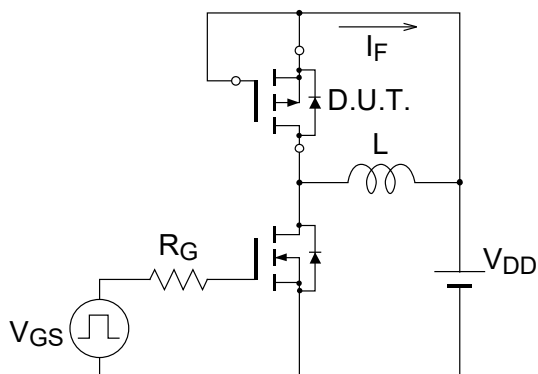


Waveform

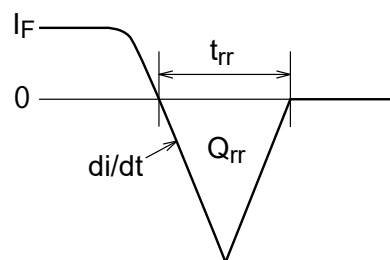


Reverse Recovery

Test Circuit



Waveform



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